July 2005

FJC1963 NPN Epitaxial Silicon Transistor

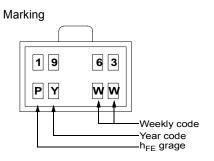


# FJC1963 NPN Epitaxial Silicon Transistor

## Audio Power Amplifier Applications

- Complement to FJC1308
- High Collector Current
- Low Collector-Emitter Saturation Voltage





## Absolute Maximum Ratings $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
Ι <sub>C</sub>	Collector Current (DC)	3	A
P <sub>C</sub>	Power Dissipation(T <sub>C</sub> =25°C)	0.5	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

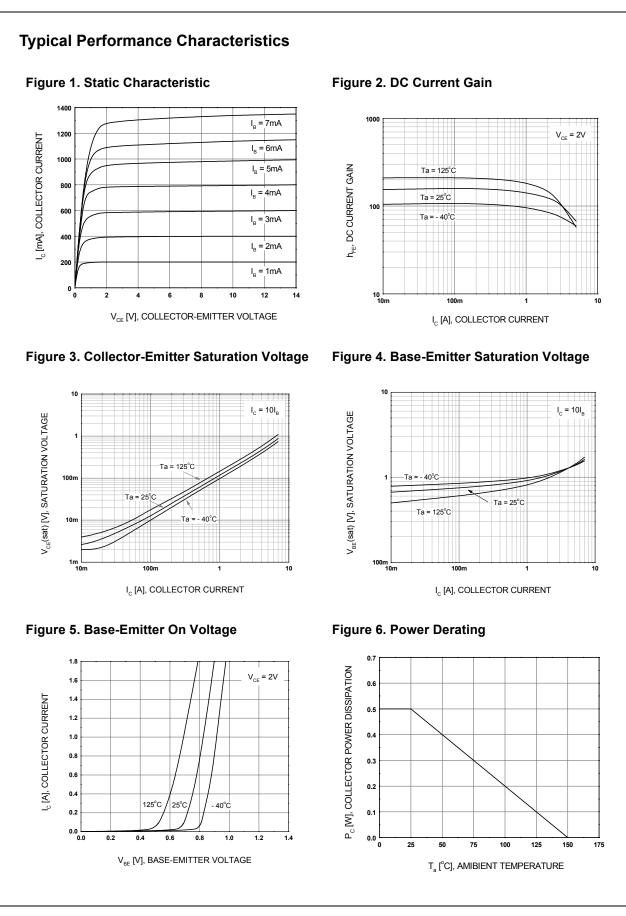
Symbol	Parameter	Test Condition	Min.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 50μA, I <sub>E</sub> = 0	50		V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 1mA, I <sub>B</sub> = 0	30		V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 50μA, I <sub>C</sub> = 0	6		V
I <sub>CEO</sub>	Collector Cut-off Current	V <sub>CE</sub> = 40V, V <sub>B</sub> = 0		0.5	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0		0.5	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = 2V, I <sub>C</sub> = 0.5A	120	560	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1.5, I <sub>B</sub> = 0.15A		0.45	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 1.5, I <sub>B</sub> = 0.15A		1.2	V

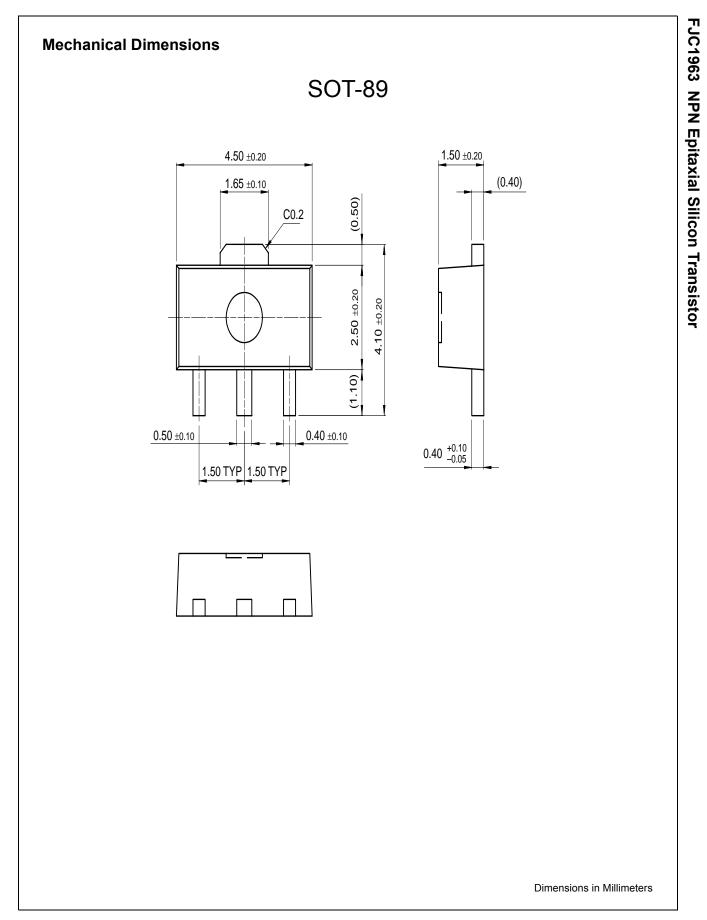
h <sub>FE</sub> Classification			
Classification	Q	R	S
h <sub>FE</sub>	120 ~ 270	180 ~ 390	280 ~ 560

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
1963	FJC1963	SOT-89	13"		4,000







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Across the board. Arour The Power Franchise <sup>®</sup> Programmable Active D		POP™ Power247™	SuperFET™ SuperSOT™-3	
Programmable Active D	roop	PowerEdge™	SuperSOT™-6	

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#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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